

IN THE SPECIFICATION

Please replace the paragraph at page 30, lines 17-23 with the following amended paragraph:

A structure of a light emitting device of the present invention is shown in FIG. 6. A first electrode 602 is formed over a substrate 601, a light emitting layer 603 is formed over the first electrode 602, a second electrode 604 is formed over the light emitting layer 603, and a transparent film 605 is formed over the second electrode. In this embodiment, the substrate in which an EL element is formed is bonded to a counter substrate 606 with an adhesive material 607, and an inert gas or resin 608 is sealed therebetween. In this embodiment, nitrogen is used for the inert gas.